

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	98763	nakayama	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/17 10:02
L2	1278	1 and (FET "field effect transistor")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/17 10:02
L3	43	2 and ("organic transistor" "organic fet" "organic channel" "organic field effect transistor" "organic thin film transistor" "polymer transistor" "organic tft")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/17 10:03
L4	3	3 and ("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/17 10:04
L5	5	("insulating layer" near4 "cured product").clm.	US-PGPUB	OR	ON	2009/06/17 10:09
L6	5	("insulating layer" near6 "phenol resin").clm.	US-PGPUB	OR	ON	2009/06/17 10:09
S1	22	("20040118520"   "20040131782"   "20050202348"   "20060081880"   "20060113523"   "20060145141"   "20060214159"   "6107117"   "6861377"   "7026231"   "7094625").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 13:40
S2	22	("20040118520"   "20040131782"   "20050202348"   "20060081880"   "20060113523"   "20060145141"   "20060214159"   "6107117"   "6861377"   "7026231"   "7094625").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:41
S3	6	S2 and pentacene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:41
S4	4	S3 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:42

S5	5586	("organic transistor" "organic fet" "organic channel" "organic field effect transistor" "organic thin film transistor" "polymer transistor" "organic tft")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:47
S6	1345	S5 and pentacene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:48
S7	523	S6 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:48
S8	93	S7 and phenol	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 15:49
S9	1	"10559799"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/19 16:07
S10	2	"2005009229"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 07:05
S11	5601	("organic transistor" "organic fet" "organic channel" "organic field effect transistor" "organic thin film transistor" "polymer transistor" "organic tft")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 09:56
S12	1351	S11 and pentacene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 09:56
S13	523	S12 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 09:56
S14	93	S13 and phenol	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 09:56
S15	1	S14 and ("phenol novolac resin" "o-cresol novolac resin" "bisphenol novolac resin" "cophenolic novolac resin")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 09:56
S16	1	S14 and ("phenol novolac" "o-cresol novolac" "bisphenol novolac resin" "cophenolic novolac")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 10:27
S17	1	S14 and ("phenol novolac" "o-cresol novolac" "bisphenol novolac" "cophenolic novolac")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 10:27
S18	2	"20070096079"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:12

S19	0	S14 and ("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:21
S20	1669	("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:23
S21	1489	S20 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:23
S22	0	S21 and phenol and pentacene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:25
S23	0	S21 and pentacene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:25
S24	1	S21 and S11	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:25
S25	0	S21 and S12	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:28
S26	3935	((257/40) or (438/99)).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2008/03/21 11:32
S27	2	S26 and ("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:32
S28	2	S27 and organic	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 11:41
S29	2	*11048909*	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 13:24
S30	7	*10048909*	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 13:25
S31	1	*10593328*	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 15:22

S32	1	*10559799"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/21 15:30
S33	22	(*20040118520"   "20040131782"   "20050202348"   "20060081880"   "20060113523"   "20060145141"   "20060214159"   "6107117"   "6861377"   "7026231"   "7094625").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:33
S34	12	S33 and (gold silver nickel)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:33
S35	0	S33 and ((gold silver nickel) near3 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:34
S36	1	S33 and ((gold silver nickel) near6 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:34
S37	4	S33 and ((gold silver nickel) near10 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:35
S38	5620	("organic transistor" "organic fet" "organic channel" "organic field effect transistor" "organic thin film transistor" "polymer transistor" "organic tft")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:37
S39	660	S38 and ((gold silver nickel) near10 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:37
S40	466	S38 and ((gold silver nickel) near5 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:38
S41	358	S38 and ((gold silver nickel) near3 (drain source))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:38
S42	158	S41 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 08:40
S43	0	S42 and (conductive near5 solution near10 (source drain gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:14
S44	14	S42 and (conductive near5 solution )	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:14
S45	0	S43 and (solution near10 (source drain gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:15

S46	23	S42 and (conductive near5 (solution dispersion paste) near10(source drain gate ))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:17
S47	2	S42 and (conductive near5 (solution dispersion paste) near10(source drain gate )) and heat	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:23
S48	139	S38 and ("thermosetting resin")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:50
S49	62	S48 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 09:50
S50	2	"2004026689"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:15
S51	1669	("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:26
S52	149	S51 and ("thermosetting resin")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:26
S53	134	S52 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:27
S54	0	S53 and ("organic transistor" "organic fet" "organic channel" "organic field effect transistor" "organic thin film transistor" "polymer transistor" "organic tft")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:27
S55	139	S38 and ("thermosetting resin")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:34
S56	62	S55 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:34
S57	2	S55 and ("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:36
S58	224	S38 and ("thermosetting ")	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/24 10:52

S59	2	S58 and ("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/24 10:52
S60	0	S53 and (( "methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")) near5 THERMOSETTING	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/24 10:59
S61	2	("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine") NEAR5 thermosetting	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/24 11:00
S62	1669	("methoxymethylated glycoluryl" "methoxymethylated melamine" "tetramethoxymethyl glycoluryl" "hexamethoxymethyl melamine")	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:05
S63	135	(source drain gate) near5 "conductive particle"	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:08
S64	93	S63 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:09
S65	47	S64 and organic	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:09
S66	7	"10064389"	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:16
S67	75	"6831769"	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:19
S68	75	"6831769"	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:20
S69	604	("source electrode" "drain electrode" "gate electrode") near5 ("conductive particle" grain "metal powder")	US-PGPUB; USPAT; EPO; JPO; DERVENT	OR	ON	2008/03/26 15:53

S70	107	S69 and organic	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/26 15:53
S71	66	S70 and @ad<"20040614"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2008/03/26 15:53
S72	2229	calixarene	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/12 11:02
S73	6	S72 and calixarene near3 (insulator insulating)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2009/06/12 11:02

6/17/2009 10:14:49 AM

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